

Abstract of the Disclosure

A method of fabricating thin film transistor TFT array discloses
ions of desired-plated metal and the graphs of the desired-plated
5 area are made by oxidation—reduction materials processes ion
replacement for implementing the metal wiring layout of the
TFT-LCDs. This, therefore, can overcome the problem of uneasy
metal etching thereto achieves the purpose of an automatic
alignment. The method uses the ability of the oxidation-reduction
10 reaction to implement the replacement for alternating the
lithography etching process in the metal wiring layout as
presented in the traditional technique.